

March 9, 2004

To: Commissioner of Patents and Trademarks
Washington, D.C. 20231

Fr: George O. Saile Reg. No. 19,572
28 Davis Avenue
Poughkeepsie, N.Y. 12603

Subject:

Divisional Patent Application of
Serial No.: 10/420,263 4/22/03

MIN-HWA CHI

NEW STORAGE ELEMENT AND SRAM CELL
STRUCTURES USING VERTICAL FETS CONTROLLED
BY ADJACENT JUNCTION BIAS THROUGH SHALLOW
TRENCH ISOLATION

PRELIMINARY AMENDMENT

Dear Sir:

This is a preliminary amendment for the above referenced Divisional Patent
Application. Please amend the above identified application for patent as follows:

CERTIFICATE OF MAILING

I hereby certify that this correspondence is being deposited with the United States
Postal Service as first class mail in an envelope addressed to: Commissioner of Patents
and Trademarks, Washington, D.C. 20231, on March 9, 2004.

Stephen B. Ackerman, Reg. No. 37,761

Signature/Date

 3/9/04

PLEASE AMEND THE SPECIFICATION AS FOLLOWS:

After the title, insert -- This is a division of Patent Application serial number 10/420,263, filing date 4/22/03, New Storage Element And Sram Cell Structures Using Vertical Fets Controlled By Adjacent Junction Bias Through Shallow Trench Isolation, assigned to the same assignee as the present invention, which is herein incorporated by reference in its entirety.

REMARKS

A reference to the parent case has been added by Preliminary Amendment to this Divisional Patent Application.

The application is believed to be in condition for allowance. Allowance of the subject Patent Application is therefore respectfully requested.

Respectfully submitted,

A handwritten signature in black ink, appearing to read 'S. B. Ackerman', with a stylized flourish at the end.

STEPHEN B. ACKERMAN, REG. NO. 37,761